

SANYO**LFB01, 01L**

Silicon Planar Leadless Type

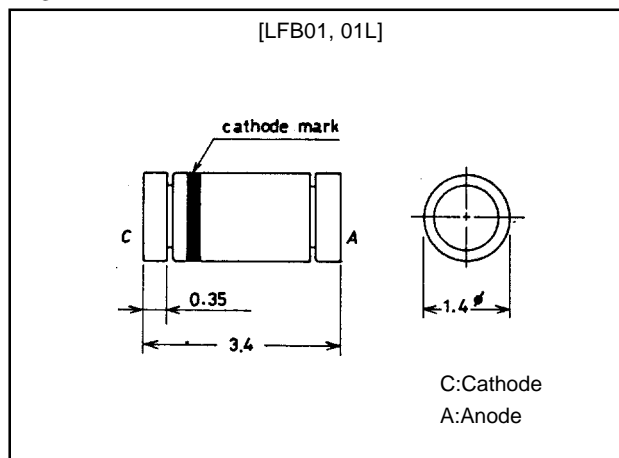
Ultrahigh-Speed Switching Diode**Features**

- Highly reliable leadless glass sleeve structure.
- Very small size.
- Capable of being surface-mounted.
- Forward voltage : $V_F \text{ max}=1.2\text{V}$.
- Interterminal capacitance : $C \text{ max}=3\text{pF}$.
- Reverse recovery time : $t_{rr} \text{ max}=4\text{ns}$.

Package Dimensions

unit:mm

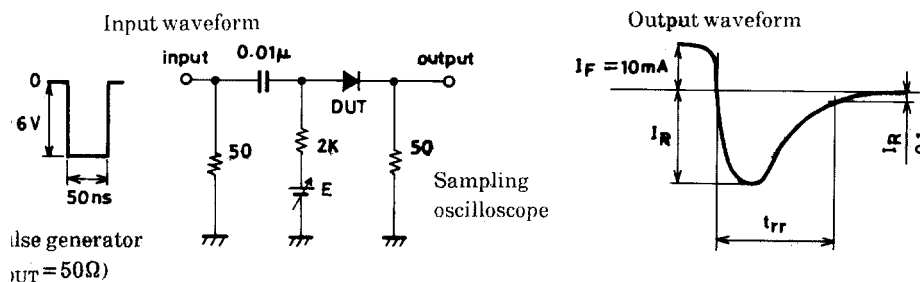
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**Specifications****Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$**

Parameter	Symbol	Conditions	LFB01L	LFB01	Unit
Peak Reverse Voltage	V_{RM}		55	90	V
Reverse Voltage	V_R		50	80	V
Peak Forward Current	I_{FM}		→	480	mA
Average Rectified Current	I_O		→	150	mA
Surge Current	I_{FSM}		→	2	A
Allowable Power Dissipation	P		→	300	mW
Junction Temperature	T_J		→	+175	$^\circ\text{C}$
Storage Temperature	T_{stg}		→	-65 to +175	$^\circ\text{C}$

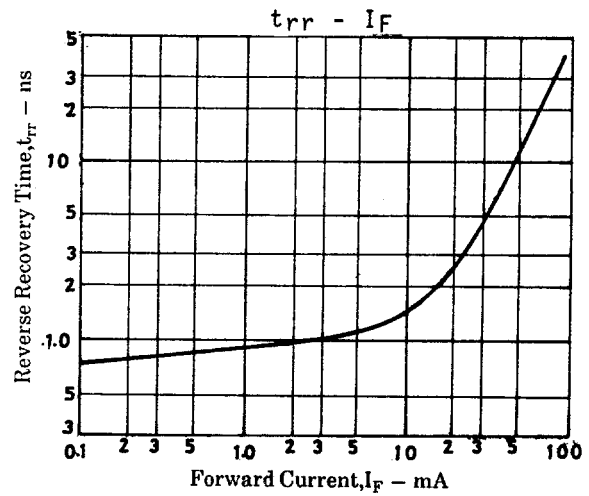
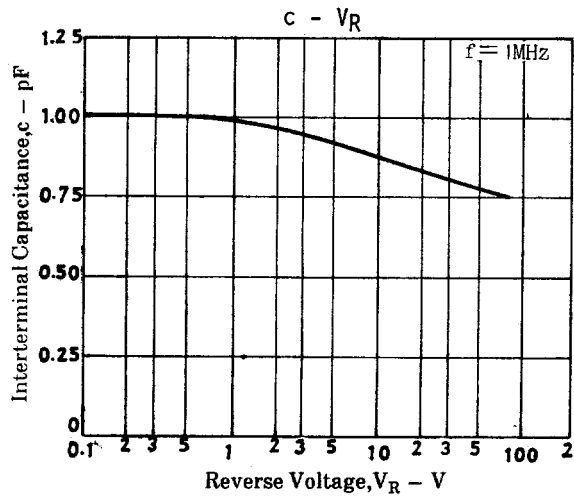
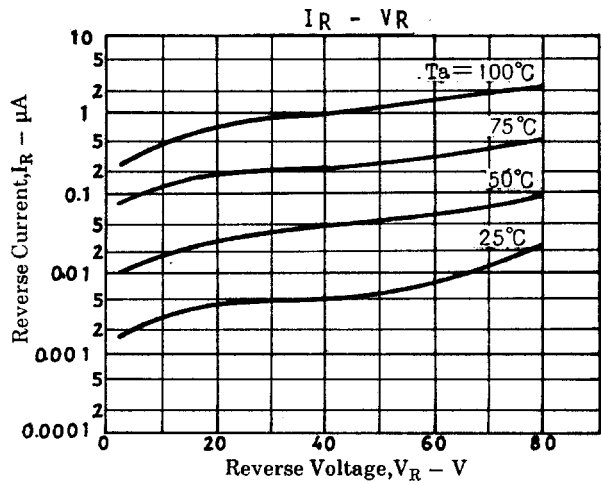
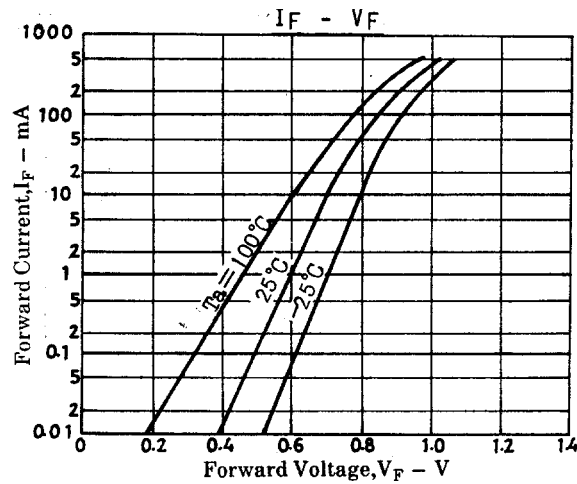
Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Forward Voltage	V_F	$I_F=100\text{mA}$			1.2	V
Reverse Current	I_{R1}	$V_R=30\text{V}$			0.1	μA
	I_{R2}	At each V_R			0.5	μA
Interterminal Capacitance	C	$V_R=0\text{V}$, $f=1\text{MHz}$			3	pF
Reverse Recovery Time	t_{rr}	$V_R=6\text{V}$, $I_F=10\text{mA}$, $R_L=50\Omega$			4	ns

Reverse Recovery Time (t_{rr}) Test CircuitUnit (resistance : Ω , capacitance :F)

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